2SK0065 (2SK65)

Silicon N-Channel Junction FET

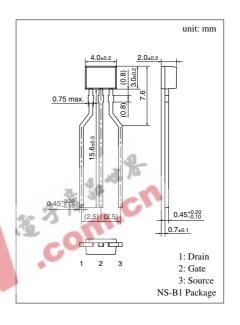
For impedance conversion in low frequency For electret capacitor microphone

■ Features

- Diode is connected between gate and source
- Low noise voltage

■ Absolute Maximum Ratings (Ta = 25°C)

| Parameter | Symbol | Ratings | Unit | |
|-------------------------------|------------------|-------------|------|--|
| Drain to Source voltage | V _{DSO} | 12 | V | |
| Gate to Drain voltage | V _{GDO} | -12 | V | |
| Drain to Source current | I_{DSO} | 2 | mA | |
| Drain to Gate current | I_{DGO} | 2 | mA | |
| Gate to Source current | I_{GSO} | 2 | mA | |
| Allowable power dissipation | P _D | 20 | mW | |
| Operating ambient temperature | Topr | -10 to +70 | °C | |
| Storage temperature | T _{stg} | -20 to +150 | °C | |
| | | | • | |



■ Electrical Characteristics (Ta = 25°C)

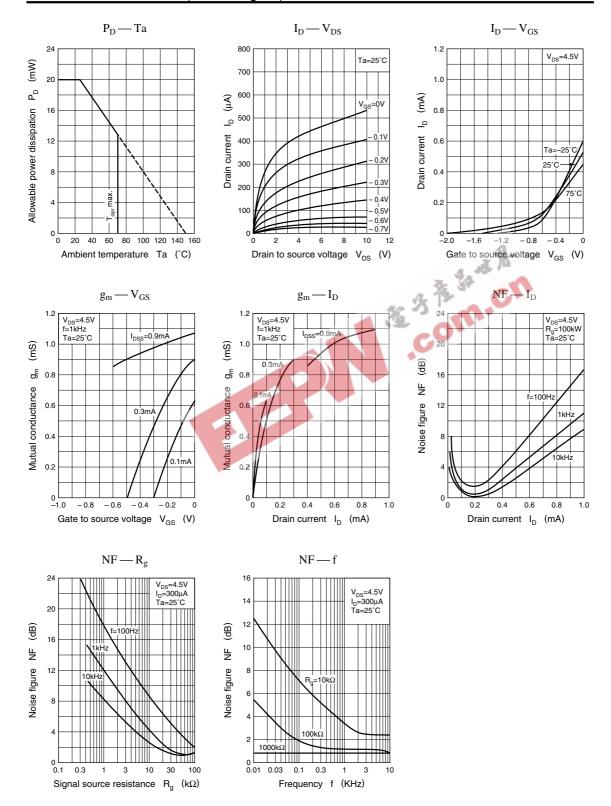
| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---------------------------------|--------------------|---|------|------|-----|------|
| Drain to Source cut-off current | I _{DSS} * | $V_{DS} = 4.5V, V_{GS} = 0, R_S = 2.2k\Omega \pm 1\%$ | 0.04 | | 0.8 | mA |
| Mutual conductance | g _m | $V_{DS} = 4.5V, V_{GS} = 0$ | 200 | 500 | | c |
| | | $R_S = 2.2k\Omega \pm 1\%$, $f = 1kHz$ | 300 | | | μS |
| Noise figure | NV | $V_{DS} = 4.5V, R_S = 2.2k\Omega \pm 1\%$ | | | 4 | μV |
| | | $C_G = 10pF$, A-curve | | | | |
| Voltage gain | G _{V1} * | $V_{DS} = 4.5 \text{V}, R_S = 2.2 \text{k}\Omega \pm 1\%$ | | 10 | | dB |
| | | $C_G = 10 \text{pF}, e_G = 100 \text{mV}, f = 70 \text{Hz}$ | | -10 | | |
| | G _{V2} * | $V_{DS} = 12V, R_S = 2.2k\Omega \pm 1\%$ | | -9.5 | | dB |
| | | $C_G = 10 \text{pF}, e_G = 100 \text{mV}, f = 70 \text{Hz}$ | | -9.3 | | |
| | G _{V3} * | $V_{DS} = 1V, R_S = 2.2k\Omega \pm 1\%$ | | 11 | | 1D |
| | | $C_G = 10 \text{pF}, e_G = 100 \text{mV}, f = 70 \text{Hz}$ | | -11 | | dB |

 $^{^{\}ast}$ I_{DSS} rank classification and G_{V} value

| Runk | P | Q | |
|---|-------------|-------------|--|
| I _{DSS} (mA) | 0.04 to 0.2 | 0.15 to 0.8 | |
| $G_{V1}(dB)$ | >-13 | >-12 | |
| G_{V2} (dB) | >-12 | >-11 | |
| ${\Delta \mid G_{V1} - G_{V2} \mid (dB)}$ | < 3 | < 3 | |

Note) The part number in the parenthesis shows conventional part number.

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